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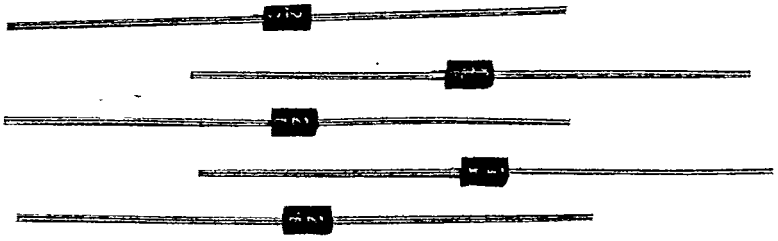
CSdc Silicon Surge Suppressors

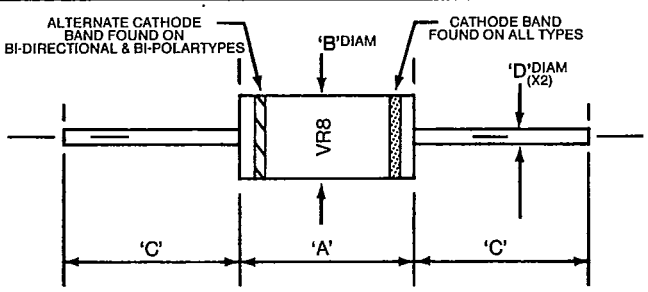
Up to 300 plus Volts Up to 100 Amps



FEATURES:

- Standard basic series covering a wide voltage selection range
- Compact size ideally suited for mounting next to the critical circuitry to be protected
- Transient power surge capacity as high as 1500 watts
- Breakdown voltages held to within a ± 10 percent tolerance
- Custom designs available with short lead times for sample and production orders
  (Note: There is a 50,000 unit minimum for production orders on all custom designs)
- Fast response time (Less than 10^{-12} seconds)
- Can be supplied taped and reeled at slight additional cost
- Wide operational and storage temperature ranges of -55°C to 125°C

MECHANICAL DATA/OUTLINE DIMENSIONS

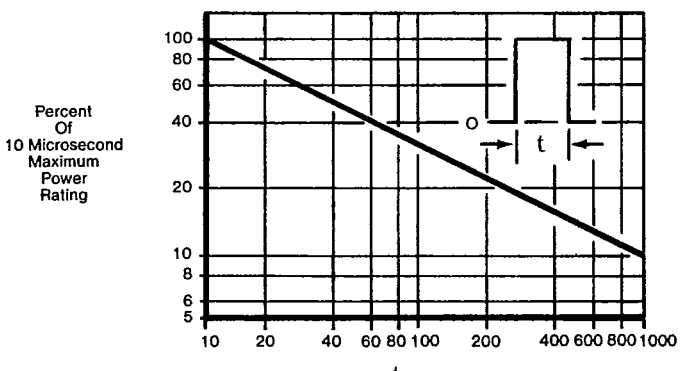


DIMENSION DETAILS

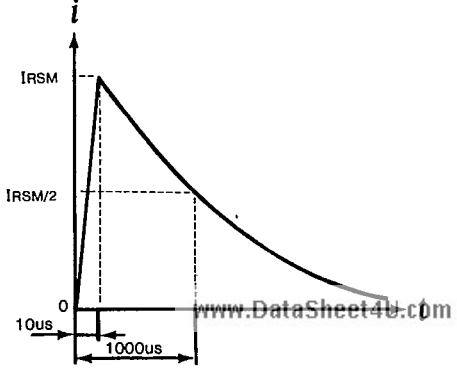
BODY CODE	UNITS	A MIN	A MAX	B MIN	B MAX	C MIN	C MAX	D MIN	D MAX
1	INCHES	—	0.310	—	0.190	0.78	—	0.029	0.033
	MILLI-METERS	—	7.870	—	4.830	19.8	—	0.736	0.840
2	INCHES	—	0.200	—	0.110	0.78	—	0.023	0.027
	MILLI-METERS	—	5.080	—	2.800	19.8	—	0.584	0.686

RATING CURVES

TRANSIENT SURGE DE-RATING SCHEDULE
(-40 C TO 125 C)



TYPICAL SURGE CURRENT TEST WAVE FORM



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SPECIFICATIONS

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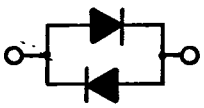
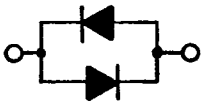
Type No.	Breakdown Voltage Bv @ $T_A = 25°C$ & $I_{BV} = 1.0$ MAPK 1/ Min. V_{PK}	Breakdown Voltage Bv @ $T_A = 25°C$ & $I_{BV} = 1.0$ MAPK 1/ Max. V_{PK}	Stand Off Voltage V_{SO} 1/ Vdc	Typical Clamping Voltage V_{clamp} @ Maximum I_{RSM} 1/ V_{PK}	Maximum Transient Surge Current, I_{TSM} for pulse widths of 1/ 2/ 10 μSec A_{PK}	Maximum Transient Surge Current, I_{TSM} for pulse widths of 1/ 2/ 1000 μSec A_{PK}	Maximum Stand Off Bias Current @ $T_A = 25°C$ & Rated V_{SO} 1/ μadc	Maximum Transient Power, P_T For Pulse Widths (Sq. Top) of 10 μSec Watts	Maximum Transient Power, P_T For Pulse Widths (Sq. Top) of 1000 μSec Watts	Typical Junction Capacitance @ Zero Bias & $T_A = 25°C$ Pfd	Body Code
 **BI-DIRECTIONAL** 											
VR84B	5.4	6.6	1.6	7.0	500	50	50	3500	350	260	1
VR88B	5.4	6.6	3.2	7.0	500	50	50	3500	350	130	1
 **UNI-POLAR** 											
SC57	6.75	8.25	6	10.5	47	4.7	200	500	50	3000	2
SC510	9.00	11.00	8	14.5	34	3.4	50	500	50	1300	2
SC518	16.20	19.80	14.5	25	20	2.0	10	500	50	600	2
SC527	24.30	29.70	21.5	38	13	1.3	10	500	50	400	2
SC550	45.0	55.0	40	72	7	0.7	10	500	50	160	2
SC5120	108.0	132.0	96	168	3	0.3	10	500	50	70	2
 **BI-POLAR** 											
SCI.5K220B	209	231	185	330	9.2	0.92	10	3000	300	300	1
SC3.5K240B	240	260	192	320	11.0	0.55	5.0	3500	350	250	1
 **BI-POLAR WITH BLOCKING DIODE** 											
SCD350	45.0	55.0	36/200 4/	70	10	1.0	10	700	70	300	2

NOTES:

1/ Both directions for bi-directional and bi-polar devices
2/ Reference typical surge current test waveform
3/ The test current for bi-direction types is 10 milli-amperes
4/ The lower voltage is bias condition for bi-polar section; higher voltage is for diode section

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